## Electronic Supplementary Material (ESI) for Nanoscale.

## Supplemental Material

## Carrier mobility and superconducting properties in monolayer oxygen-terminated functionalized MXene $\mathrm{Ti}_{2} \mathrm{CO}_{2}$

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FIG. S1: The scattering rates of the two most effective optical modes ( $\nu=10$ and 14) as functions of energy for the (a) n- and (b) p-type ( $0.01 \mathrm{el} /$ cell) $\mathrm{Ti}_{2} \mathrm{CO}_{2}$. The temperature was assumed to be 300 K .

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FIG. S2: Valley-dependent hole scattering rates $(1 / \mathrm{ps})$. Hole concentration and temperature are assumed to be $0.01 \mathrm{el} / \mathrm{cell}$ and 300 K , respectively. The possible intra/inter-valley transitions are illustrated in (a-d).


FIG. S3: The Fermi surface of the valance band consisting of $\Gamma_{2 V}$ valley.


FIG. S4: Isotropic Eliashberg spectral function $\left(\alpha^{2} F\right)$ and phonon density of states (PhDOS) for monolayer $\mathrm{Ti}_{2} \mathrm{CO}_{2}$ within both the rigid and the jellium regimes. The rigid band $\alpha^{2} F$ and PhDOS of (n-type) $-0.01 \mathrm{el} / \mathrm{cell}(\mathrm{a})$ and ( p -type) $+0.01 \mathrm{el} / \mathrm{cell}$ (b) are illustrated. (c) and (d) are the same as (a) and (b) except in the jellium regime.


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